

Docket No.: GR96P8091 D2



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applic. No. : 10/673,962 Confirmation No: 3943  
Applicant : Michael Kelly et al.  
Filed : September 29, 2003  
Title : Method of Producing a Light-Emitting Diode  
Art Unit : 2812  
Examiner : William D. Coleman

Docket No. : GR96P8091 D2  
Customer No. : 24131

INFORMATION DISCLOSURE STATEMENT

Hon. Commissioner for Patents

Sir:

In accordance with 37 C.F.R. 1.98 copies of the following patents and/or publications are submitted herewith:

Sung-Gap Lee et al.: "Preparation and Characterization of Lead Zirconate Titanate Heterolayered Thin Films on Pt/Ti/SiO<sub>2</sub>/Si Substrate by Sol-Gel Method", *Jpn. J. Appl. Phys., Vol. 38, Part I, No. 1A, January 1999, pp. 217-218*;

Y.-K. Song et al.: "A vertical cavity light emitting inGaN quantum well heterostructure", *Applied Physics Letters, Vol. 74, No. 23, June 7, 1999, pp. 3441-3443*.

Respectfully submitted,

A handwritten signature in black ink, appearing to read "W. Stemer".

For Applicants  
Date: June 7, 2005  
Lerner and Greenberg, P.A.  
Post Office Box 2480  
Hollywood, FL 33022-2480  
Tel: (954) 925-1100  
Fax: (954) 925-1101  
/bmb

WERNER H. STEMER  
REG. NO. 34,956



FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEINFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))

Attorney Docket No.:

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Applicant

Michael Kelly et al.

Filing Date

Group Art Unit

September 29, 2003

2812

## U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A						
	B						
	C						
	D						
	E						
	F						
	G						
	H						
	I						

## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J						
	K						
	L						
	M						
	N						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	O	Sung-Gap Lee et al.: "Preparation and Characterization of Lead Zirconate Titanate Heterolayered Thin Films on Pt/Ti/SiO <sub>2</sub> /Si Substrate by Sol-Gel Method", <i>Jpn. J. Appl. Phys.</i> , Vol. 38, Part I, No. 1A, January 1999, pp. 217-218
	P	Y.-K. Song et al.: "A vertical cavity light emitting inGaN quantum well heterostructure", <i>Applied Physics Letters</i> , Vol. 74, No. 23, June 7, 1999, pp. 3441-3443

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.